



# **Ultrahigh-Speed Switching Applications**

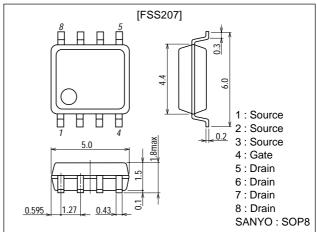
#### **Features**

- · Low ON resistance.
- · 2.5V drive.

## **Package Dimensions**

unit:mm

2116



## **Specifications**

### **Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		20	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±10	V
Drain Current (DC)	I <sub>D</sub>		10	А
Drain Current (pulse)	I <sub>DP</sub>	PW≤10µs, duty cycle≤1%	52	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (1000mm <sup>2</sup> ×0.8mm)	2	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### **Electrical Characteristics** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	20			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =20V, V <sub>GS</sub> =0			10	μA
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0			±10	μA
Cutoff Voltage	V <sub>GS(off)</sub>	$V_{DS}$ =10V, $I_{D}$ =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =10A	23	32		S
Static Drain-to-Source On-State Resistance	R <sub>DS(on)</sub> 1	I <sub>D</sub> =10A, V <sub>GS</sub> =4V		10	13	mΩ
	R <sub>DS(on)</sub> 2	I <sub>D</sub> =2A, V <sub>GS</sub> =2.5V		15	21	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		1700		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		1200		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =10V, f=1MHz		680		pF

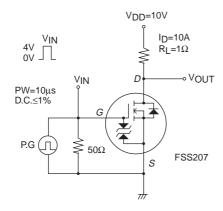
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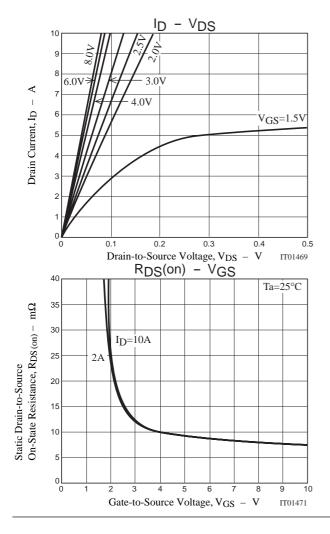
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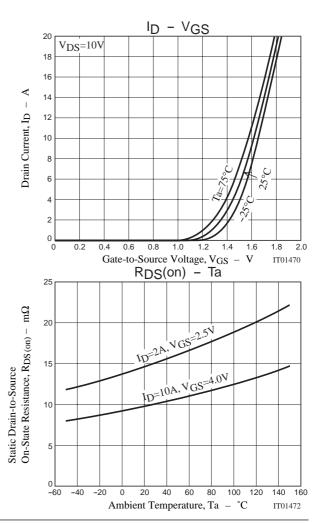
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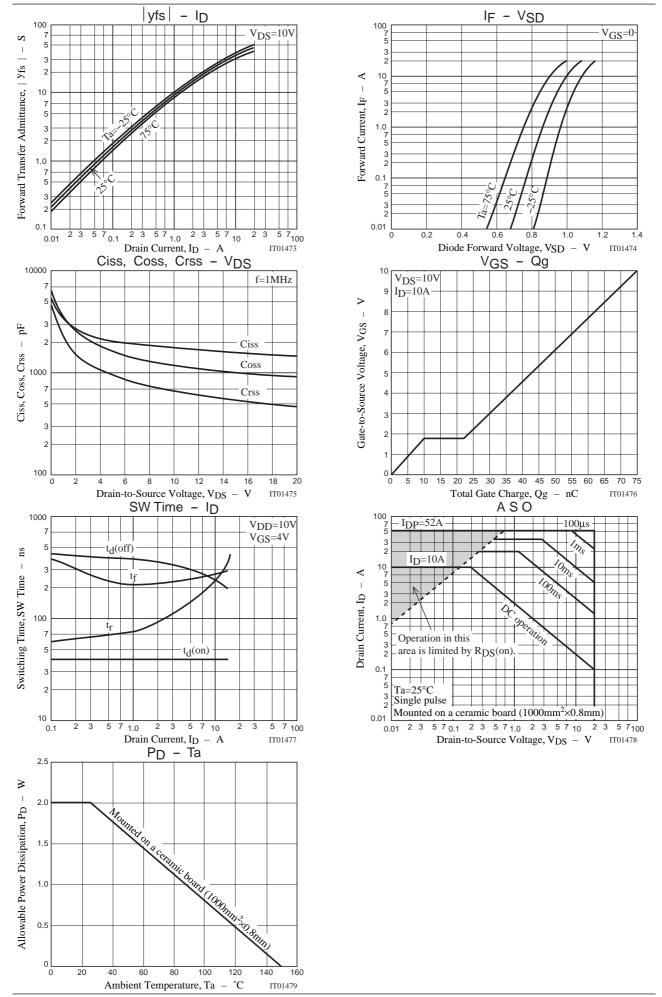
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	O I III
Turn-ON Delay Time	t <sub>d(on)</sub>	See specified Test Circuit		40		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit		260		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit		260		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		280		ns
Total Gate Charge	Qg	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =10A		75		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =10A		10		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =10A		12		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =10A, V <sub>GS</sub> =0		1.0	1.2	V

## **Switching Time Test Circuit**









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